

Rev. 1.7 00

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AUTOMOTIVE, 105°C OPERATION, VOLTAGE MONITORING IC WITH CELL BALANCING FUNCTION

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The S-19190 Series is a voltage monitoring IC with a cell balancing function and includes a high-accuracy voltage detection circuit and a delay circuit.

The S-19190 Series is suitable for cell balancing and overcharge protection of batteries and capacitors.

Caution This product can be used in vehicle equipment and in-vehicle equipment. Before using the product for these purposes, it is imperative to contact our sales representatives.

Features

• High-accuracy voltage detection c	ircuit	
Cell balancing detection voltage:	2.0 V to 4.6 V (5 mV step)	Accuracy $\pm 12 \text{ mV} (2.0 \text{ V} \le \text{V}_{\text{BU}} < 2.4 \text{ V})$
		Accuracy $\pm 0.5\%$ (2.4 V \leq V _{BU} \leq 4.6 V)
Cell balancing release voltage:	2.0 V to 4.6 V*1	Accuracy $\pm 24 \text{ mV} (2.0 \text{ V} \le \text{V}_{\text{BL}} < 2.4 \text{ V})$
		Accuracy $\pm 1.0\%$ (2.4 V $\leq V_{BL} \leq 4.6$ V)
Overcharge detection voltage:	2.0 V to 4.6 V (5 mV step)	Accuracy $\pm 12 \text{ mV} (2.0 \text{ V} \le \text{V}_{CU} < 2.4 \text{ V})$
		Accuracy $\pm 0.5\%$ (2.4 V \leq V _{CU} \leq 4.6 V)
Overcharge release voltage:	2.0 V to 4.6 V*2	Accuracy $\pm 24 \text{ mV} (2.0 \text{ V} \le \text{V}_{CL} < 2.4 \text{ V})$
		Accuracy $\pm 1.0\%$ (2.4 V \leq V _{CL} \leq 4.6 V)
	1111111111111	

• Built-in Nch transistor with ON resistance of 5 Ω typ. between the CB pin and the VSS pin

- Current consumption: $2.0 \ \mu A \ max. \ (Ta = +25^{\circ}C)$
- Delay times are generated only by an internal circuit (External capacitors are unnecessary).

• CO pin output form and output logic are selectable: CMOS output Active "H", active "L"

- Nch open-drain output Active "H", active "L"
- Switchable to power-saving mode by using the $\overline{\text{CE}}$ pin
- Operation temperature range: Ta = -40°C to +105°C
- Lead-free (Sn 100%), halogen-free
- AEC-Q100 qualified^{*3}
- *1. Cell balancing release voltage = Cell balancing detection voltage Cell balancing hysteresis voltage (Cell balancing hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.7 V in 50 mV step.)
- *2. Overcharge release voltage = Overcharge detection voltage Overcharge hysteresis voltage (Overcharge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.7 V in 50 mV step.)
- ***3.** Contact our sales representatives for details.

Applications

- Rechargeable battery module
- Capacitor module

Package

• SOT-23-6

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Block Diagram



*1. All diodes shown in the figure are parasitic diodes.

Figure 1

■ AEC-Q100 Qualified

This IC supports AEC-Q100 for operation temperature grade 2. Contact our sales representatives for details of AEC-Q100 reliability specification.

Product Name Structure

1. Product name



*1. Refer to the tape drawing.

2. Package

Table 1	Package	Drawing	Codes
14010 1	. aonago	_	00400

Package Name	Dimension	Таре	Reel
SOT-23-6	MP006-A-P-SD	MP006-A-C-SD	MP006-A-R-SD

3. Product name list

Table 2 (2 / 1)										
Product Name	Cell Balancing Detection	Cell Balancing Release	Overcharge Detection	Overcharge Release	CO Pin	CO Pin	Combination of			
Product Name	Voltage [V _{BU}]	Voltage [V _{BL}]	Voltage [V _{CU}]	Voltage [V _{CL}]	Output Form	Output Logic	Delay Time			
S-19190AAH-M6T1U	2.600 V	2.600 V	2.750 V	2.750 V	CMOS output	Active "H"	(1)			
S-19190ABH-M6T1U	3.000 V	3.000 V	3.150 V	3.150 V	CMOS output	Active "H"	(1)			
S-19190ACH-M6T1U	3.000 V	3.000 V	3.200 V	3.200 V	CMOS output	Active "H"	(1)			
S-19190ADH-M6T1U	3.100 V	3.100 V	3.250 V	3.250 V	CMOS output	Active "H"	(1)			
S-19190AEH-M6T1U	3.100 V	3.100 V	3.300 V	3.300 V	CMOS output	Active "H"	(1)			
S-19190AFH-M6T1U	2.600 V	2.600 V	2.800 V	2.800 V	CMOS output	Active "H"	(1)			
S-19190AGH-M6T1U	2.400 V	2.400 V	2.900 V	2.900 V	CMOS output	Active "H"	(1)			
S-19190AHH-M6T1U	2.400 V	2.400 V	3.000 V	3.000 V	CMOS output	Active "H"	(1)			
S-19190AIH-M6T1U	2.100 V	2.100 V	3.000 V	3.000 V	CMOS output	Active "H"	(1)			
S-19190AKH-M6T1U	2.400 V	2.400 V	3.200 V	3.200 V	CMOS output	Active "H"	(1)			
S-19190ALH-M6T1U	2.100 V	2.000 V	3.200 V	3.200 V	CMOS output	Active "H"	(1)			
S-19190AMH-M6T1U	2.620 V	2.520 V	2.800 V	2.700 V	CMOS output	Active "H"	(1)			
S-19190ANH-M6T1U	3.300 V	3.300 V	4.080 V	3.930 V	CMOS output	Active "H"	(1)			
S-19190AOH-M6T1U	2.000 V	2.000 V	3.000 V	3.000 V	CMOS output	Active "H"	(1)			
S-19190APH-M6T1U	3.700 V	3.700 V	4.500 V	4.500 V	CMOS output	Active "H"	(1)			
S-19190AQH-M6T1U	3.800 V	3.800 V	4.080 V	3.930 V	CMOS output	Active "H"	(1)			
S-19190ARH-M6T1U	2.800 V	2.800 V	3.150 V	3.150 V	CMOS output	Active "H"	(1)			

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				2 (2 / 2)			
Product Name	Cell Balancing Detection Voltage [V _{BU}]	Cell Balancing Release Voltage [V _{BL}]	Overcharge Detection Voltage [Vcu]	Overcharge Release Voltage [VcL]	CO Pin Output Form	CO Pin Output Logic	Combination of Delay Time
S-19190ASH-M6T1U	2.800 V	2.800 V	3.200 V	3.200 V	CMOS output	Active "H"	(1)
S-19190ATH-M6T1U	2.800 V	2.800 V	3.100 V	3.100 V	CMOS output	Active "H"	(1)
S-19190AUH-M6T1U	2.500 V	2.400 V	3.800 V	3.700 V	CMOS output	Active "H"	(1)
S-19190AVH-M6T1U	2.300 V	2.200 V	3.800 V	3.700 V	CMOS output	Active "H"	(1)
S-19190AWH-M6T1U	2.650 V	2.600 V	2.750 V	2.650 V	Nch open-drain output	Active "L"	(1)
S-19190AXH-M6T1U	2.400 V	2.400 V	2.950 V	2.950 V	CMOS output	Active "H"	(1)
S-19190AYH-M6T1U	4.150 V	4.150 V	4.275 V	4.275 V	CMOS output	Active "H"	(2)
S-19190AZH-M6T1U	2.450 V	2.450 V	2.500 V	2.500 V	CMOS output	Active "H"	(3)
S-19190BCH-M6T1U	4.200 V	4.200 V	4.300 V	4.200 V	CMOS output	Active "L"	(5)
S-19190BDH-M6T1U	2.300 V	2.300 V	2.600 V	2.600 V	CMOS output	Active "H"	(1)
S-19190BEH-M6T1U	4.400 V	4.200 V	4.600 V	4.600 V	CMOS output	Active "H"	(3)
S-19190BFH-M6T1U	3.550 V	3.200 V	4.080 V	3.380 V	CMOS output	Active "L"	(4)
S-19190BGH-M6T1U	2.700 V	2.000 V	4.400 V	3.700 V	CMOS output	Active "H"	(3)
S-19190BHH-M6T1U	3.550 V	3.550 V	3.800 V	3.700 V	CMOS output	Active "L"	(4)
S-19190BIH-M6T1U	2.700 V	2.000 V	4.400 V	4.200 V	CMOS output	Active "H"	(3)
S-19190BJH-M6T1U	2.725 V	2.675 V	2.775 V	2.725 V	CMOS output	Active "L"	(4)
S-19190BKH-M6T1U	2.700 V	2.000 V	4.080 V	3.930 V	CMOS output	Active "H"	(3)
S-19190BLH-M6T1U	4.150 V	3.950 V	4.600 V	3.900 V	CMOS output	Active "L"	(4)
S-19190BMH-M6T1U	3.550 V	3.450 V	4.000 V	3.300 V	CMOS output	Active "L"	(4)
S-19190BNH-M6T1U	2.700 V	2.650 V	3.100 V	2.800 V	CMOS output	Active "H"	(1)

Table 2 (2 / 2)

Remark 1. Please contact our sales representatives for products other than the above.

2. Set $V_{CU} > V_{BU}$.

3. Refer to Table 3 for details about combinations of delay times.

Т	ał	ble	е :	3

O anabia ati an af	Cell Balancing	Cell Balancing	Overcharge	Overcharge Release
Combination of	Detection Delay Time	Release Delay Time	Detection Delay Time	Delay Time
Delay Time	[t _{BU}]	[t _{BL}]	[tcu]	[t _{CL}]
(1)	128 ms	1.0 ms	128 ms	1.0 ms
(2)	128 ms	1.0 ms	1024 ms	1.0 ms
(3)	64 ms	0.5 ms	64 ms	0.5 ms
(4)	128 ms	1.0 ms	1024 ms	2.0 ms
(5)	64 ms	2.0 ms	256 ms	1.0 ms

Remark The delay times can be changed within the ranges listed above. For details, please contact our sales representatives.

Table 4								
Delay Time	Symbol			Sele	ection Ran	ge		Remark
Cell balancing detection delay time ^{*1}	tвu	64 ms	128 r	ns*²	256 ms	512 m	s 1024 ms	Select a value from the left.
Cell balancing release delay time	t _{BL}	0.5 m	8	1.0 ms*2			2.0 ms	Select a value from the left.
Overcharge detection delay time*1	tcu	64 ms	128 ms*2		256 ms	512 m	s 1024 ms	Select a value from the left.
Overcharge release delay time	tc∟	0.5 m	8		1.0 ms*²		2.0 ms	Select a value from the left.

*1. Set $t_{CU} \ge t_{BU}$.

***2.** The value is the delay time of the standard products.

Pin Configuration

1. SOT-23-6



Figure 2

	Table 5						
Pin No.	Symbol	Description					
1	СО	Output pin for overcharge signal					
2	VSS	Input pin for negative power supply					
3	DP	Test mode switching pin "H": Test mode (used to shorten the delay time) "L": Normal operation mode					
4	CE	Power-saving mode switching pin "H": Power-saving mode "L": Normal operation mode					
5	VDD	Input pin for positive power supply					
6	СВ	Output pin for cell balancing signal (Nch open-drain output)					

■ Absolute Maximum Ratings

		Table 6		
			(Ta = +25°C unless otherwise	specified)
Item	Symbol	Applied Pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin	Vds	VDD	Vss - 0.3 to Vss + 6.0	V
Input pin voltage	VIN	CE, DP	$V_{\text{SS}}-0.3$ to $V_{\text{DD}}+0.3 \leq V_{\text{SS}}+6.0$	V
Output pin voltage	Vout	CO, CB	$V_{\text{SS}}-0.3$ to $V_{\text{DD}}+0.3 \leq V_{\text{SS}}+6.0$	V
Output pin current	Ісв	СВ	100 (-40°C to +105°C)	mA
Operation ambient temperature	T _{opr}	_	-40 to +105	°C
Storage temperature	T _{stg}	_	-55 to +125	°C

Table 6

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

■ Thermal Resistance Value

		Table 7					
Item	Symbol	Cone	Condition			Max.	Unit
Junction-to-ambient thermal resistance*1		SOT-23-6	Board A	_	159	_	°C/W
	θја		Board B	_	124		°C/W
			Board C	_	_	-	°C/W
			Board D	_	_	-	°C/W
			Board E	-	-	-	°C/W

*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "**■ Power Dissipation**" and **"Test Board**" for details.

Electrical Characteristics

For details about the test circuits and testing method, refer to "■ Test Circuit".

Caution Unless otherwise specified in Table 8 and Table 9, set V2 = V3 = 0 V, and SWn (n = 1 to 4) = OFF. 1 Ta = $\pm 25^{\circ}$ C

1. Ta = +25°C	
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			(Ta =	+25°C un	less othe	rwise spe	ecified
Item	Symbol	Condition		Min.	Тур.	Max.	Unit
Detection voltage	-						
Cell balancing detection	V _{BU}	SW1 = ON	$2.0~V \leq V_{BU} < 2.4~V$	V _{в∪} – 0.012	VBU	V _{BU} + 0.012	V
voltage	VBU	3001 - 010	$2.4~V \leq V_{BU} \leq 4.6~V$	V _{в∪} × 0.995	V_{BU}	V _{BU} × 1.005	V
Cell balancing release		SW4 - ON	$2.0~V \leq V_{BL} < 2.4~V$	V _{BL} – 0.024	VBL	V _{BL} + 0.024	V
voltage	Vbl	SW1 = ON	$2.4~V \leq V_{BL} \leq 4.6~V$	$V_{BL} \times 0.99$	VBL	V _{BL} × 1.01	V
Overcharge detection	Vcu	$2.0 \text{ V} \leq V_{\text{CU}}$	< 2.4 V	V _{CU} – 0.012	Vcu	V _{CU} + 0.012	V
voltage	VCU	$2.4 \text{ V} \leq V_{CU}$	$2.4~V \leq V_{CU} \leq 4.6~V$		V _{CU}	V _{CU} × 1.005	V
Overcharge release	Mai	$2.0 V \le V_{CL} < 2.4 V$ $2.4 V \le V_{CL} \le 4.6 V$		V _{CL} – 0.024	Vcl	V _{CL} + 0.024	V
voltage	V _{CL}			V _{CL} × 0.99	Vcl	V _{CL} × 1.01	V
Input voltage							
Operation voltage between VDD pin and VSS pin	Vds	Voltages output from CO pin and CB pin are fixed		1.5	-	5.0	V
CE pin voltage "H"	$V_{\overline{CEH}}$	-		-	-	V _{DD} × 0.9	V
CE pin voltage "L"	$V_{\overline{CEL}}$	_		V _{DD} × 0.1	Ι	-	V
DP pin voltage "H"	V _{DPH}	-		-	-	V _{DD} × 0.9	V
DP pin voltage "L"	Vdpl	-		V _{DD} × 0.1	-	-	V
Input current	•	•				•	
Current consumption during operation	IOPE	IVDD when V	I_{VDD} when V1 = V _{BL} – 0.1 V		1.2	2.0	μA
Current consumption during power-saving	IPSV	IVDD when V	$V1 = V2 = V_{BL} - 0.1 V$	_	_	0.1	μΑ

Table 8 (1 / 2)

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		Table 8 (2 / 2) (Ta :	= +25°C ur	less othe	erwise spe	cified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Delay time						
Cell balancing detection delay time	t _{BU}	_	$t_{\text{BU}} \times 0.8$	tвu	$t_{BU} imes 1.2$	ms
Cell balancing release delay time	t _{BL}	_	$t_{\text{BL}} \times 0.8$	t _{BL}	$t_{\text{BL}} \times 1.2$	ms
Overcharge detection delay time	tcu	-	$t_{\text{CU}} \times 0.8$	tcu	$t_{CU} imes 1.2$	ms
Overcharge release delay time	tc∟	-	$t_{\text{CL}} \times 0.8$	tc∟	$t_{\text{CL}} imes 1.2$	ms
Output current						
CB pin output current					.	
CB pin sink current	ICBS	$V1 = V_{BU} + 0.1 V$, SW2 = ON, V4 = 0.5 V	30	_	_	mA
CB pin leakage current	ICBL	V1 = V _{BL} – 0.1 V, SW2 = ON, V4 = 6.0 V	-	_	0.1	μA
CO pin output current (out	put form:	CMOS output, output logic: acti	ve "H")			
CO pin sink current	Icol	V1 = V _{CL} – 0.1 V, SW4 = ON, V5 = 0.5 V	5.0	_	-	mA
CO pin source current	Ісон	V1 = V _{CU} + 0.1 V, SW4 = ON, V5 = V1 – 0.5 V	1.0	_	-	mA
CO pin output current (out	put form:	CMOS output, output logic: acti	ve "L")			
CO pin sink current	Icol	V1 = V _{CU} + 0.1 V, SW4 = ON, V5 = 0.5 V	5.0	_	_	mA
CO pin source current	Ісон	V1 = V _{CL} – 0.1 V, SW4 = ON, V5 = V1 – 0.5 V	1.0	_	_	mA
CO pin output current (out	put form:	Nch open-drain output, output l	ogic: activ	/e "H")		
CO pin sink current	Icol	V1 = V _{CL} – 0.1 V, SW4 = ON, V5 = 0.5 V	5.0	_	-	mA
CO pin leakage current	ICOHL	V1 = V _{CU} + 0.1 V, SW4 = ON, V5 = 6.0 V	-	_	0.1	μA
CO pin output current (out	put form:	Nch open-drain output, output l	ogic: activ	/e "L")		
CO pin sink current	Icol	V1 = V _{CU} + 0.1 V, SW4 = ON, V5 = 0.5 V	5.0	_	-	mA
CO pin leakage current	ICOHL	$V1 = V_{CL} - 0.1 V$, SW4 = ON, V5 = 6.0 V	-	_	0.1	μA

Table 8 (2 / 2)

2. Ta = -40° C to $+105^{\circ}$ C

		Tabl	e 9 (1 / 2) (Ta = -40°C to +	105°C un	less othe	rwise sp	ecified)
Item	Symbol		Condition	Min.	Тур.	Max.	Unit
Detection voltage						•	
Cell balancing detection	V	SW(1 - ON	$2.0~V \leq V_{BU} < 2.4~V$	V _{BU} – 0.040	V _{BU}	V _{BU} + 0.040	V
voltage	V _{BU}	SW1 = ON	$2.4~V \leq V_{BU} \leq 4.6~V$	V _{BU} × 0.984	V _{BU}	V _{BU} × 1.016	V
Cell balancing release	V	SW1 = ON	$2.0~V \leq V_{BL} < 2.4~V$	V _{BL} – 0.080	VBL	V _{BL} + 0.080	V
voltage	V _{BL}	5001 = ON	$2.4~V \leq V_{BL} \leq 4.6~V$	$V_{BL} imes 0.968$	VBL	V _{BL} × 1.032	V
Overcharge detection	V	$2.0 \text{ V} \leq V_{CU}$	< 2.4 V	V _{CU} – 0.040	Vcu	V _{CU} + 0.040	V
voltage	Vcu	$2.4~V \leq V_{CU} \leq 4.6~V$		V _{CU} × 0.984	Vcu	V _{CU} × 1.016	V
Overcharge release		$2.0 V \le V_{CL} < 2.4 V$ $2.4 V \le V_{CL} \le 4.6 V$		V _{CL} – 0.080	Vcl	V _{CL} + 0.080	V
voltage	V _{CL}			V _{CL} × 0.968	Vcl	V _{CL} × 1.032	V
Input voltage						•	
Operation voltage between VDD pin and VSS pin	V _{DS}	Voltages output from CO pin and CB pin are fixed		1.5	_	5.0	V
CE pin voltage "H"	V _{CEH}	-		_	_	V _{DD} × 0.9	V
CE pin voltage "L"	VTEL		_	V _{DD} × 0.1	_	_	V
DP pin voltage "H"	Vdph	_		_	_	V _{DD} × 0.9	V
DP pin voltage "L"	Vdpl	_		V _{DD} × 0.1	_	_	V
Input current		•					•
Current consumption during operation	IOPE	IVDD when V	$V1 = V_{BL} - 0.1 V$	_	1.2	2.1	μΑ
Current consumption during power-saving	I _{PSV}	I_{VDD} when V	$V1 = V2 = V_{BL} - 0.1 V$	_	_	0.15	μA

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		Table 9 (2 / 2) (Ta = -40°C to	+105°C un	less othe	erwise spe	cified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Delay time	_					
Cell balancing detection delay time	t _{BU}	_	$t_{\text{BU}} \times 0.5$	tвu	t _{в∪} × 1.5	ms
Cell balancing release delay time	t _{BL}	_	$t_{\text{BL}} \times 0.5$	t _{BL}	$t_{\text{BL}} imes 1.5$	ms
Overcharge detection delay time	tcu	_	$t_{\text{CU}} \times 0.5$	tcu	$t_{CU} imes 1.5$	ms
Overcharge release delay time	tc∟	_	$t_{\text{CL}} \times 0.5$	tc∟	$t_{\text{CL}} \times 1.5$	ms
Output current						
CB pin output current			· · · ·		i	i
CB pin sink current	ICBS	$V1 = V_{BU} + 0.1 V$, SW2 = ON, V4 = 0.5 V	30	_	-	mA
CB pin leakage current	ICBL	V1 = V _{BL} – 0.1 V, SW2 = ON, V4 = 6.0 V	-	_	0.15	μA
CO pin output current (out	put form:	CMOS output, output logic: acti	ve "H")			
CO pin sink current	Icol	V1 = V _{CL} – 0.1 V, SW4 = ON, V5 = 0.5 V	5.0	_	-	mA
CO pin source current	Ісон	V1 = V _{CU} + 0.1 V, SW4 = ON, V5 = V1 – 0.5 V	1.0	_	-	mA
CO pin output current (out	put form:	CMOS output, output logic: acti	ve "L")			
CO pin sink current	Icol	V1 = V _{CU} + 0.1 V, SW4 = ON, V5 = 0.5 V	5.0	_	_	mA
CO pin source current	Ісон	V1 = V _{CL} – 0.1 V, SW4 = ON, V5 = V1 – 0.5 V	1.0	_	_	mA
CO pin output current (out	put form:	Nch open-drain output, output l	ogic: activ	/e "H")		
CO pin sink current	Icol	V1 = V _{CL} – 0.1 V, SW4 = ON, V5 = 0.5 V	5.0	_	_	mA
CO pin leakage current	Ісонь	V1 = V _{CU} + 0.1 V, SW4 = ON, V5 = 6.0 V	-	_	0.15	μA
CO pin output current (out	put form:	Nch open-drain output, output l	ogic: activ	/e "L")	·	
CO pin sink current	Icol	$V1 = V_{CU} + 0.1 V$, SW4 = ON, V5 = 0.5 V	5.0	_	_	mA
CO pin leakage current	Ісонь	$V1 = V_{CL} - 0.1 V$, SW4 = ON, V5 = 6.0 V	_	_	0.15	μA

Test Circuit



Figure 3

Caution Unless otherwise specified in Table 8, set V2 = V3 = 0 V, and SWn (n = 1 to 4) = OFF.

1. CE pin voltage "H"

 \overline{CE} pin voltage "H" (V_{CEH}) is defined as the voltage at which I_{VDD} is changed from I_{OPE} to I_{PSV} when V2 is increased from 0 V after setting V1 = V_{BL} – 0.1 V.

2. CE pin voltage "L"

 \overline{CE} pin voltage "L" (V_{CEL}) is defined as the voltage at which I_{VDD} is changed from I_{PSV} to I_{OPE} when V2 is decreased from V_{BL} - 0.1 V after setting V1 = V2 = V_{BL} - 0.1 V.

3. DP pin voltage "H"*1

DP pin voltage "H" (V_{DPH}) is defined as the voltage at which the test mode is switched when V3 is increased from 0 V after setting V1 = $V_{BL} - 0.1$ V.

4. DP pin voltage "L" *1

DP pin voltage "L" (V_{DPL}) is defined as the voltage at which the normal operation mode is switched when V3 is decreased from $V_{BL} - 0.1$ V after setting V1 = V3 = $V_{BL} - 0.1$ V.

5. Cell balancing detection delay time

Cell balancing detection delay time (t_{BU}) is defined as the time from when SW1 is set to ON and V1 is set to V_{BU} – 0.1 V to when the CB pin output is inverted after setting V1 to V_{BU} + 0.1 V.

6. Cell balancing release delay time

Cell balancing release delay time (t_{BL}) is defined as the time from when SW1 is set to ON and V1 is set to V_{BL} + 0.1 V to when the CB pin output is inverted after setting V1 to V_{BL} – 0.1 V.

7. Overcharge detection delay time

Overcharge detection delay time (t_{CU}) is defined as the time from when SW1 is set to ON and V1 is set to V_{CU} – 0.1 V to when the CO pin output is inverted after setting V1 to V_{CU} + 0.1 V.

8. Overcharge release delay time

Overcharge release delay time (t_{CL}) is defined as the time from when SW1 is set to ON and V1 is set to V_{CL} + 0.1 V to when the CO pin output is inverted after setting V1 to V_{CL} – 0.1 V.

*1. For details about switching to the test mode by using the DP pin, refer to "5. DP pin" in "
Operation".

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Standard Circuit





Table 10 Constants for External Components

Symbol	Part	Purpose	Min.	Тур.	Max.	Remark
Rvdd	Resistor	ESD protection, for power fluctuation control	150 Ω	330 Ω	1.0 kΩ	Resistance should be as small as possible to avoid worsening the overcharge detection accuracy due to current consumption.*1
CVDD	Capacitor	For power fluctuation control	0.068 μF	0.1 μF	1.0 μF	Connect a capacitor of 0.068 μ F or more between VDD pin and VSS pin.*1
Rсв	Resistor	For setting the cell balancing current value	_	_	_	Set the required cell balancing current value depending on "2. Cell balancing status" in "■ Operation".*2

*1. When connecting a resistor less than 150 Ω to R_{VDD} or a capacitor less than 0.068 µF to C_{VDD}, the S-19190 Series may malfunction when power is largely fluctuated.

*2. Set the cell balancing current value so that R_{CB} does not exceed the power dissipation.

Caution 1. The constants may be changed without notice.

2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.

Operation

Remark Refer to "■ Standard Circuit ".

1. Normal status

In the S-19190 Series, if the voltage between the VDD pin and the VSS pin (V_{DS}) has not reached the cell balancing detection voltage (V_{BU}), the CB pin output is in the high-impedance status. The CO pin output status varies according to the output form and output logic selected, as shown in **Table 11**. This is the normal status.

Table 11						
CO Pin Output Form and Output Logic	CB Pin Output	CO Pin Output				
CMOS output, active "H"	"H"	"L"				
CMOS output, active "L"	"H"	"H"				
Nch open-drain output, active "H"	"H"	"L"				
Nch open-drain output, active "L"	"H"	"H"				

2. Cell balancing status

In the S-19190 Series, if V_{DS} is V_{BU} or higher and this status continues for the cell balancing detection delay time (t_{BU}) or longer, the CB pin output becomes "L". This is the cell balancing status.

The cell balancing status is released when V_{DS} drops to the cell balancing release voltage (V_{BL}) or lower and this status continues for the cell balancing release delay time (t_{BL}) or longer.

The S-19190 Series includes an Nch transistor with ON resistance of 5 Ω typ. (R_{CBON}) between the CB pin and the VSS pin, thus causing the cell balancing current (I_{CB}) to flow in cell balancing status, and the cell balancing operation to start.

By connecting a resistor (R_{CB}) to the CB pin, I_{CB} in cell balancing status can be calculated by using the following equation.





Figure 5

3. Overcharge status

In the S-19190 Series, if V_{DS} is the overcharge detection voltage (V_{CU}) or higher and this status continues for the overcharge detection delay time (t_{CU}) or longer, the CO pin output is inverted. The CO pin output status varies according to the output form and output logic selected, as shown in **Table 12**. This is the overcharge status. In the overcharge status, the CB pin output becomes "L".

Table 12					
CO Pin Output Form and Output Logic	CB Pin Output	CO Pin Output			
CMOS output, active "H"	"L"	"H"			
CMOS output, active "L"	"L"	"L"			
Nch open-drain output, active "H"	"L"	"H"			
Nch open-drain output, active "L"	"L"	"L"			

The overcharge status is released when V_{DS} drops to the overcharge release voltage (V_{CL}) or lower and this status continues for the overcharge release delay time (t_{CL}) or longer.

4. CE pin

The S-19190 Series has the \overline{CE} pin (Power-saving mode switching pin). The S-19190 Series is set to the power-saving mode by inputting a voltage of $V_{\overline{CE}H}$ or higher to the \overline{CE} pin.

Table 13				
CE Pin	Status			
Open (V _{CE} = V _{SS})	Normal operation mode			
$"H" (V_{\overline{CE}} \ge V_{\overline{CEH}})$	Power-saving mode			
$"L" (V_{\overline{CE}} \le V_{\overline{CE}L})$	Normal operation mode			

In the power-saving mode, the current consumption is decreased to current consumption during power-saving (I_{PSV}). Also, in the power-saving mode, almost all operations are stopped, and the CB pin or the CO pin output is the same as in the normal status.

The \overline{CE} pin is pulled down to V_{SS} by the internal resistor. When in a mode other than power-saving mode, leave the \overline{CE} pin open or short it with V_{SS}.

5. DP pin

The S-19190 Series has the DP pin (Test mode switching pin). The S-19190 Series is set to test mode (used to shorten the delay time) by inputting a voltage of V_{DPH} or higher to the DP pin.

Table 14				
DP Pin	Status			
Open (V _{DP} = V _{SS})	Normal operation mode			
"H" (V _{DP} ≥ V _{DPH})	Test mode			
"L" ($V_{DP} \leq V_{DPL}$)	Normal operation mode			

In test mode, the cell balancing detection delay time (t_{BU}) and overcharge detection delay time (t_{CU}) are shortened to 1/64 of the delay time in the normal operation mode.

The DP pin is pulled down to V_{SS} by the internal resistor. When in a mode other than test mode, leave the DP pin open or short it with V_{SS} .

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■ Timing Chart



*1. The CB pin is pulled up by the external resistor.

- *2. (1): Normal status
 - (2): Cell balancing status
 - (3): Overcharge status

Remark The charger is assumed to charge with a constant current.

Figure 6

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Precautions

- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
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■ Characteristics (Typical Data)

1. Current consumption

1.1 IOPE vs. Ta





2. Cell balancing detection / release voltage, overcharge detection / release voltage and delay times



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2.5 t_{BU} vs. Ta







3. Output current

3.1 ICBL VS. VCB



3. 3 Ісон vs. Vco

















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Power Dissipation

SOT-23-6



Board	Power Dissipation (P _D)
А	0.63 W
В	0.81 W
С	_
D	_
E	_

SOT-23-3/3S/5/6 Test Board

) IC Mount Area

(1) Board A



Item		Specification		
Size [mm]		114.3 x 76.2 x t1.6		
Material		FR-4		
Number of copper foil layer		2		
	1	Land pattern and wiring for testing: t0.070		
	2	-		
Copper foil layer [mm]	3	-		
	4	74.2 x 74.2 x t0.070		
Thermal via		-		

(2) Board B



Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
- Copper foil layer [mm] -	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

No. SOT23x-A-Board-SD-2.0







No. MP006-A-P-SD-2.1

TITLE	SOT236-A-PKG Dimensions
No.	MP006-A-P-SD-2.1
ANGLE	$\bigoplus \leftarrow]$
UNIT	mm
ABLIC Inc.	





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